



IXTU08N100P Information



For Reference Only

Part Number IXTU08N100P

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1000V 8A TO-251

Package TO-251-3 Short Leads, IPak, TO-251AA

For the pricing/inventory/lead time, please contact $% \left(\frac{1}{2}\right) =\left(\frac{1}{2}\right) \left(\frac{1}{2}\right)$

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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IXTU08N100P Specifications

Manufacturer Part Number IXTU08N100P Manufacturer IXYS Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package TO-251-3 Short Leads, IPak, TO-251AA Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 1000V Current - Continuous Drain (Id) @ 25°C 8A (Tc) Drive Voltage (Max Rds On, Min Rds On) - Vgs(th) (Max) @ Id - Gate Charge (Qg) (Max) @ Vgs - Input Capacitance (Ciss) (Max) @ Vds - Vgs (Max) - FET Feature - Power Dissipation (Max) - Rds On (Max) @ Id, Vgs - Operating Temperature - Mounting Type Through Hole Supplier Device Package TO-251 Package / Case TO-251-3 Short Leads, IPak, TO-251AA		
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Operating Temperature - Mounting Type Through Hole Supplier Device Package TO-251 Package / Case TO-251-3 Short Leads, IPak, TO-251AA	Power Dissipation (Max)	-
Mounting Type Through Hole Supplier Device Package TO-251 Package / Case TO-251-3 Short Leads, IPak, TO-251AA	Rds On (Max) @ Id, Vgs	-
Supplier Device Package TO-251 Package / Case TO-251-3 Short Leads, IPak, TO-251AA	Operating Temperature	-
Package / Case TO-251-3 Short Leads, IPak, TO-251AA	Mounting Type	Through Hole
	Supplier Device Package	TO-251
Report errors?	Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
		Report errors?

IXTU08N100P Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTU08N100P Payment Methods



















IXTU08N100P Shipping Methods













If you have any question about IXTU08N100P, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com